DATA SHEET

μ**PD77015,77017,77018** 

MOS INTEGRATED CIRCUIT

#### 16 bits, Fixed-point Digital Signal Processor

 $\mu$ PD77015, 77017, 77018 are 16 bits fixed-point DSPs (Digital Signal Processors) developed for digital signal processing with its demand for high speed and precision.

#### FEATURES

FUNCTIONS

EC

- Instruction cycle: 30 ns (MIN.)
  - Operation clock: 33 MHz
  - External clock: 33, 16.5, 8.25, 4.125 MHz
  - Crystal: 33 MHz
- · On-chip PLL to provide higher operation clock than the external clock
- Dual load/store
- Hardware loop function
- Conditional execution
- · Executes product-sum operation in one instruction cycle
- PROGRAMMING
  - + 16 bits  $\times$  16 bits + 40 bits  $\rightarrow$  40 bits multiply accumulator
  - 8 general registers (40 bits each)
  - 8 ROM/RAM data pointer: each data memory area has 4 registers
  - 10 source interrupts (external: 4, internal: 6)
  - 3 operand instructions (example: R0 = R0 +R1L\*R2L)
  - Nonpipeline on execution stage
- MEMORY AREAS
  - Instruction memory area : 64K words  $\times$  32 bits
  - Data memory areas : 64K words  $\times$  16 bits  $\times$  2 (X memory, Y memory)
- CLOCK GENERATOR
  - Mask option for CLKOUT pin:
    - Fixed to the low level.
    - Does not output the internal system clock.
  - Selectable source clock: external clock input and crystal resonator

#### [External clock]

On-chip PLL to provide higher operation clock (33 MHz MAX.) than the external clock.

Variable multiple rates (1, 2, 4, 8) by mask option.

[Crystal resonator]

Oscillation frequency corresponds directly to the system clock frequency (Sure to specify the mask option frequency multiple as "1").

## In this document, all descriptions of the $\mu$ PD77017 also apply to the $\mu$ PD77015 and $\mu$ PD77018, unless otherwise specified.

The information in this document is subject to change without notice.



- ON-CHIP PERIPHERAL
  - I/O port: 4 bits
  - Serial I/O (16 bits): 2 channels
  - Host I/O (8 bits): 1 channel
- CMOS
- +3 V single power supply

#### ORDERING INFORMATION

Part Number	Package
μPD77015GC-×××-9EU	100-pin plastic TQFP (FINE PITCH) (14 $ imes$ 14 mm)
$\mu$ PD77017GC-×××-9EU	100-pin plastic TQFP (FINE PITCH) (14 $ imes$ 14 mm)
$\mu$ PD77018GC-×××-9EU	100-pin plastic TQFP (FINE PITCH) (14 $ imes$ 14 mm)

**Remark** ××× indicates a code suffix.

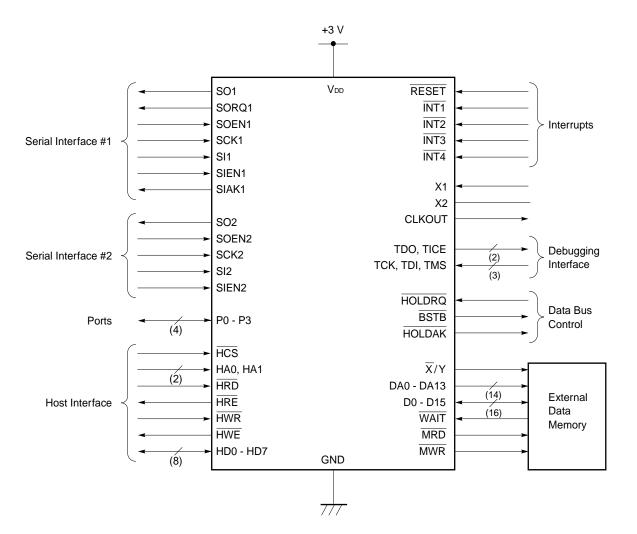
X–Bus ₹₹ External Memory Y–Bus X Memory Y Memory X Memory Data Y Memory Data Serial I/O #1 R0-R7 Pointers Pointers Serial I/O #2 Main Bus ALU (40) MPY Ports 16×16+40 →40 Loop Control Instruction Memory Interrupt Control PC Stack Stack Host I/O CPU Control Wait Controller WAIT RESET CLKOUT X1 X2  $\overline{INT1} - \overline{INT4}$ IE I/O

BLOCK DIAGRAM

Z

 $\mu$ PD77015, 77017, 77018

#### FUNCTIONAL PIN GROUPS



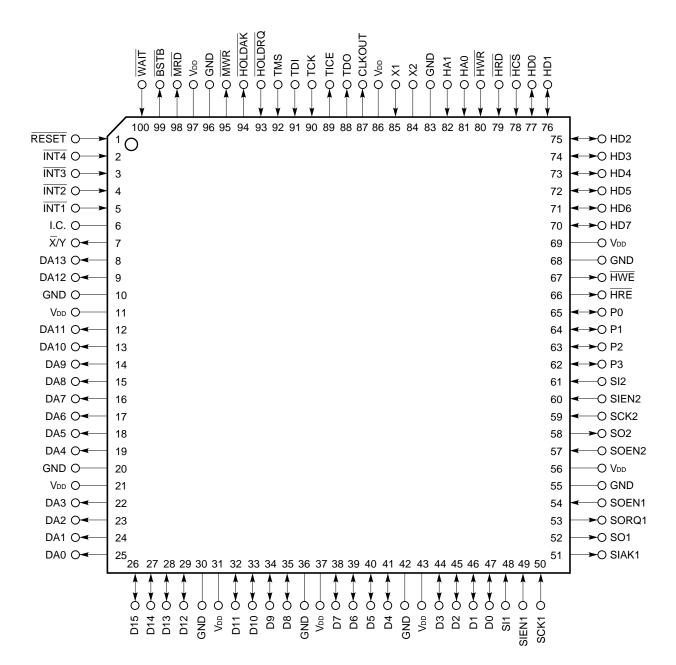
## µPD77015, 77017, 77018

#### **★** Functional Differences among the $\mu$ PD7701× Family

Item	μPD77016	μPD77015	μPD77017	μPD77018	μPD77018A	μPD77019
Internal instruction RAM	1.5K words	256 words 4K words				
Internal instruction ROM	None	4K words	12K words		24K words	
External instruction memory	48K words			None		
Data RAM (X/Y memory)	2K words each	1K words each	2K words each		3K words each	
Data ROM (X/Y memory)	None	2K words each	4K words each		12K words each	
External data memory	48K words each			16K words each		
Instruction cycle (Maximum operation speed)		30 ns (33 MHz) 19 ns (52 MHz)				
External clock (at maximum operation speed)	66 MHz	33/16.5/8.25/4.125 MHz Variable multiple rate (1, 2, 4, 8 ) by mask option.			Variable multiple ra	3/ 13/6.5 MHz te (1, 2, 3, 4, 8 ) by option.
Crystal (at maximum operation speed)	_		33 MHz	52	MHz	
Instruction	-		ST	OP instruction is ad	ded.	
Serial interface (2 Channels)	Channel 1 has the same functions as channel 2.	<sup>2</sup> Channel 1 has the same functions as that of the $\mu$ PD77016. Channel 2 has no SORQ2 or SIAK2 pin (Channel 2 is used for CODEC connection).				ion).
Power supply	5V	3 V				
Package	160-pin plastic QFP			100-pin plastic TQF	P	

#### PIN CONFIGURATION

100-pin plastic TQFP (FINE PITCH) (14  $\times$  14 mm ) (Top View)



#### PIN IDENTIFICATION

BSTB:	Bus Strobe
CLKOUT:	Clock Output
D0-D15:	16 Bits Data Bus
DA0-DA13:	External Data Memory Address Bus
GND:	Ground
HA0,HA1:	Host Data Access
HCS:	Host Chip Select
HD0-HD7:	Host Data Bus
HOLDAK:	Hold Acknowledge
HOLDRQ:	Hold Request
HRD:	Host Read
HRE:	Host Read Enable
HWE:	Host Write Enable
HWR:	Host Write
I.C.:	Internally connection
INT1-INT4:	Interrupt
MRD:	Memory Read Output
MWR:	Memory Write Output
P0-P3:	Port
RESET:	Reset
SCK1,SCK2:	Serial Clock Input
SI1,SI2:	Serial Data Input
SIAK1:	Serial Input Acknowledge
SIEN1,SIEN2:	Serial Input Enable
SO1,SO2:	Serial Data Output
SOEN1,SOEN2	Serial Output Enable
SORQ1:	Serial Output Request
TCK:	Test Clock Input
TDI:	Test Data Input
TDO:	Test Data Output
TICE:	Test In-Circuit Emulator
TMS:	Test Mode Select
VDD:	Power Supply
WAIT:	Wait Input
X1:	Clock input/crystal connection
X2:	Crystal connection
$\overline{X}/Y$ :	X/Y Memory Select

#### PIN NAME

Pin No.	Symbol	Pin No.	Symbol	Pin No.	Symbol	Pin No.	Symbol
1	RESET	26	D15	51	SIAK1	76	HD1
2	INT4	27	D14	52	SO1	77	HD0
3	INT3	28	D13	53	SORQ1	78	HCS
4	INT2	29	D12	54	SOEN1	79	HRD
5	INT1	30	GND	55	GND	80	HWR
6	I.C. Note	31	Vdd	56	Vdd	81	HA0
7	<del></del> <del>X</del> /γ	32	D11	57	SOEN2	82	HA1
8	DA13	33	D10	58	SO2	83	GND
9	DA12	34	D9	59	SCK2	84	X2
10	GND	35	D8	60	SIEN2	85	X1
11	Vdd	36	GND	61	SI2	86	Vdd
12	DA11	37	Vdd	62	P3	87	CLKOUT
13	DA10	38	D7	63	P2	88	TDO
14	DA9	39	D6	64	P1	89	TICE
15	DA8	40	D5	65	P0	90	тск
16	DA7	41	D4	66	HRE	91	TDI
17	DA6	42	GND	67	HWE	92	TMS
18	DA5	43	Vdd	68	GND	93	HOLDRQ
19	DA4	44	D3	69	Vdd	94	HOLDAK
20	GND	45	D2	70	HD7	95	MWR
21	Vdd	46	D1	71	HD6	96	GND
22	DA3	47	D0	72	HD5	97	Vdd
23	DA2	48	SI1	73	HD4	98	MRD
24	DA1	49	SIEN1	74	HD3	99	BSTB
25	DA0	50	SCK1	75	HD2	100	WAIT

Note I.C. (Internally Connected): Leave this pin open.

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#### 1. PIN FUNCTIONS

#### 1.1 Pin Functions

#### • Power supply

Symbol	Pin No.	I/O	Function
Vdd	11, 21, 31, 37, 43, 56, 69, 86, 97	-	+3V power supply
GND	10, 20, 30, 36, 42, 55, 68, 83, 96	_	Ground

#### System control

Symbol	Pin No.	I/O	Function
X1	85	I	<ul><li>Clock input / crystal connection pin</li><li>The clock signal is connected to X1, when using external clock for system clock.</li></ul>
X2	84	_	Crystal connection pin • X2 should be left open when using external clock for system clock.
CLKOUT	87	0	Internal system clock output
RESET	1	I	Internal system reset signal input

#### Interrupt

Symbol	Pin No.	I/O	Function
INT4 - INT1	2 - 5	I	Maskable external interrupt input <ul> <li>Falling edge detection</li> </ul>

#### • External data memory interface

Symbol	Pin No.	I/O	Function
Χ̈́/Υ	7	0 (3S)	<ul><li>Memory select signal output</li><li>0: X memory is used.</li><li>1: Y memory is used.</li></ul>
DA13 - DA0	8, 9, 12 -19, 22 - 25	O (3S)	<ul> <li>Address bus to external data memory</li> <li>External data memory is accessed.</li> <li>During the external memory is not accessed, these pins keep the previous level.</li> <li>These pins are set to low level; 0000H, by reset.</li> <li>They continue outputting low level until the first external memory access.</li> </ul>
D15 - D0	26 -29, 32 - 35, 38 - 41, 44 - 47	I/O (3S)	<ul><li>16 bits data bus to external data memory</li><li>External data memory is accessed.</li></ul>
MRD	98	0 (3S)	Read output <ul> <li>Reads external memory</li> </ul>
MWR	95	O (3S)	Write output <ul> <li>Writes external memory</li> </ul>
WAIT	100	I	<ul> <li>Wait signal input</li> <li>Wait cycle is input when external memory is read.</li> <li>1: No wait</li> <li>0: Wait</li> </ul>
HOLDRQ	93	I	<ul><li>Hold request signal input</li><li>Input low level when external data memory bus is expected to use.</li></ul>
BSTB	99	0	<ul> <li>Bus strobe signal output</li> <li>Outputs low level while the μPD77017 is occupying external memory bus.</li> </ul>
HOLDAK	94	0	<ul> <li>Hold acknowledge signal output</li> <li>Outputs low level when the μPD77017 permits external device to use external data memory bus.</li> </ul>

**Remark** The state of the pins added 3S becomes high impedance when bus release signal ( $\overline{HOLDAK} = 0$ ) is output.

#### • Serial interface

Symbol	Pin No.	I/O	Function
SCK1	50	I	Clock input for serial 1
SORQ1	53	0	Serial output 1 request
SOEN1	54	I	Serial output 1 enable
SO1	52	O (3S)	Serial data output 1
SIEN1	49	I	Serial input 1 enable
SI1	48	I	Serial data input 1
SCK2	59	I	Clock input for serial 2
SOEN2	57	I	Serial output 2 enable
SO2	58	O (3S)	Serial data output 2
SIEN2	60	I	Serial input 2 enable
SI2	61	I	Serial data input 2
SIAK1	51	0	Serial input 1 acknowledge

**Remark** The state of the pins added 3S becomes high impedance, when data output have been finished or **RESET** is input.

#### • Host interface

Symbol	Pin No.	I/O	Function
HA1	82	I	Specifies register which HD7 to HD0 access 1: Accesses HST: Host interface status register when HA1 = 0 0: Accesses HDT(in): Host transmit data register when $\overline{HWR} = 0$ 0: Accesses HDT(out): Host receive data register when $\overline{HRD} = 0$
HAO	81	I	<ul> <li>Specifies bits of registers which HD7 to HD0 access</li> <li>1: Accesses bits 15-8 of HST, HDT(in) or HDT(out)</li> <li>0: Accesses bits 7-0 of HST, HDT(in) or HDT(out)</li> </ul>
HCS	78	I	Chip select input
HRD	79	I	Host read input
HWR	80	I	Host write input
HRE	66	0	Host read enable output
HWE	67	0	Host write enable output
HD7 - HD0	70 - 77	I/O (3S)	8 bits host data bus

Remark The state of the pins added 3S becomes high impedance when the host does not access host interface.

#### • I/O port

Symbol	Pin No.	I/O	Function
P3 - P0	62 - 65	I/O	I/O port

#### Debugging interface

Symbol	Pin No.	I/O	Function
TDO	88	О	For debugging
TICE	89	0	For debugging
тск	90	I	For debugging
TDI	91	I	For debugging
TMS	92	I	For debugging

#### • Other

Symbol	Pin No.	I/O	Function
I.C.	6	_	Internal connected pin. Leave this pin open. Caution When any signal is applied to or read out from this pin, normal operation of the $\mu$ PD77017 is not assured.

#### 1.2 Recommended Connection for Unused Pins

Pin	I/O	Recommended connection
INT1 - INT4	I	connect to VDD
X/Y	0	open
DA0 - DA13	0	
D0 - D15 <sup>Note1</sup>	I/O	connect to VDD or GND, via a resistor
MRD	0	open
MWR	0	
WAIT	I	connect to VDD
HOLDRQ	I	
BSTB	0	open
HOLDAK	0	
SCK1, SCK2	I	connect to V <sub>DD</sub> or GND
SI1, SI2	I	
SOEN1, SOEN2	I	connect to GND
SIEN1, SIEN2	I	
SORQ1	0	open
SO1, SO2	0	
SIAK1	0	
HA0, HA1	I	connect to VDD or GND
HCS	I	connect to VDD
HRD	I	
HWR	I	
HRE	0	open
HWE	0	
HD0 - HD7 <sup>Note2</sup>	I/O	connect to V <sub>DD</sub> or GND, via a resistor
P0 - P3	I/O	
тск	I	connect to GND, via a resistor
TDO, TICE	0	open
TMS, TDI	I	open(pull-up internally)
CLKOUT	0	open

**Note 1.** Can leave open, if no access to external data memory is executed in the whole of program.

**2.** Can leave open, if  $\overline{\text{HCS}}$ ,  $\overline{\text{HRD}}$ ,  $\overline{\text{HWR}}$  are fixed to high level.

#### Remark I: Input pin

- O: Output pin
- I/O: Input/Output pin

#### 2. FUNCTIONS

#### 2.1 Pipeline Processing

This section describes the  $\mu$ PD77017 pipeline processing.

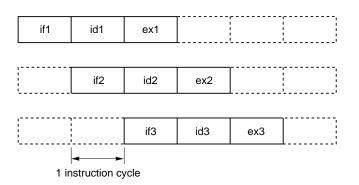
#### 2.1.1 Outline

The  $\mu$ PD77017 basic operations are executed in following 3-stage pipeline.

- (1) instruction fetch; if
- (2) Instruction decoding; id
- (3) execution; ex

When the  $\mu$ PD77017 operates a result of a instruction just executed before, the data is input to ALU in parallel with written back to general registers. Pipeline processing actualizes programming without delay time to execute instructions and write back data. Three successive instructions and their processing timing are shown below.

#### **Pipeline Processing Timing**



#### 2.1.2 Instructions with Delay

The following instructions have delay time in execution.

(1) Instructions to control interrupt

2 instruction cycles have been taken between instruction fetch and execution.

(2) Inter-register transfer instructions and immediate data set instructions When data is set in data pointer, it needs 2 instruction cycles before the data is valid.



#### 2.2 Program Control Unit

Program control unit controls not only count up of program counter in normal operation, but loop, repeat, branch, halt and interrupt.

In addition to loop stack of loop 4 level and program stack of 15 level, software stack can be used for multiloop and multi-interrupt/subroutine call.

The  $\mu$ PD77017 has external 4 interruptions and internal 6 interruptions from peripheral, and specifies interrupt enable or disable independently.

The HALT and STOP instructions cause the  $\mu$ PD77017 to place in low power standby mode.

When the HALT instruction is executed, power consumption decreases. HALT mode is released by interrupt input or hardware reset input. It takes several system clock to recover.

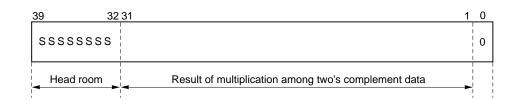
When the STOP instruction is executed, power consumption decreases. STOP mode is released by hardware reset input. It takes a few ms to recover.

#### 2.3 Operation Unit

Operation unit consists of the following five parts.

- 40 bits general register  $\times$  8 for data load/store and input/output of operation data
- 16 bits  $\times$  16 bits + 40 bits  $\rightarrow$  40 bits multiply accumulator
- 40 bits Data ALU
- 40 bits barrel shifter
- SAC: shifter and count circuit.

Standard word length is 40 bits to make overflow check and adjustment easy, and to accumulate the result of 16 bits  $\times$  16 bits multiplication correctly.



#### 2.3.1 General register (R0 to R7)

The  $\mu$ PD77017 has eight 40 bits registers for operation input/output and load/store with memory. General register consists of the following three parts.

- R0L to R7L (bit 15 to bit 0)
- R0H to R7H (bit 31 to bit 16)
- R0E to R7E (bit 39 to bit 32)

But each of RnL, RnH and RnE are treated as a register in the following conditions.

#### (1) General register used as 40 bits register

General registers are treated as 40 bits register, when they are used for the following aims.

- (a) Operand for triminal operation (except for multiplier input)
- (b) Operand for dyadic operation (except for multiplier and shift value)
- (c) Operand for monadic operation (except for exponent instructions)
- (d) Operand for operation
- (e) Operand for conditional judge
- (f) Destination for load instruction (with sign extension and 0 clear)

#### (2) General register used as 32 bits register

Bit 31 to bit 0 of general register are treated as 32 bits register, when it is used for a operand of exponent instruction.

#### (3) General register used as 24 bits register

Bit 39 to bit 16 of general register are treated as 24 bits register, when it is used for destination with extended sign for a load/store instruction.

#### (4) General register used as 16 bits register

Bit 31 to bit 16 of general register are treated as 16 bits register, when it is used for the following aims.

- (a) Signed operand for multiplier
- (b) Source/destination for load/store instruction

Bit 15 to bit 0 of general register are treated as 16 bits register, when it is used for the following aims.

- (c) Unsigned operand for multiplier
- (d) Shift value for shift instruction
- (e) Source/destination for load/store instruction
- (f) Source/destination for inter-register transfer instruction
- (g) Destination for immediate data set instruction
- (f) Hardware loop times

#### (5) General register used as 8 bits register

Bit 39 to bit 32 of general register are treated as 8 bits register, when it is used for source/destination of load/ store instruction.

#### 2.3.2 MAC: Multiply ACcumulator

MAC multiplies a pair of 16 bits data, and adds or subtract the result and 40 bits data. MAC outputs 40 bits data.

MAC operates three types of multiplication: signed data  $\times$  signed data, signed data  $\times$  unsigned data and unsigned data  $\times$  unsigned data.

Result of multiplication and 40 bits data for addition can be added after 1 or 16 bits arithmetic shift right.

#### 2.3.3 ALU: Arithmetic Logic Unit

ALU performs arithmetic operation and logic operation. Both input/output data are 40 bits.

#### 2.3.4 BSFT: Barrel ShiFTer

BSFT performs shift right/left operation. Both input/output data are 40 bits. There are two types of shift right operations; arithmetic shift right which sign is extended, and logic shift right which is input 0 in MSB first.

#### 2.3.5 SAC: Shifter And Count Circuit

SAC calculates and outputs shift value for normalization. SAC is input 32 bits data and outputs the 40 bits data. Then, bit 39 to bit 5 of output data is always 0.

#### 2.3.6 CJC: Condition Judge Circuit

CJC judges whether condition is true or false with 40 bits input data. A conditional instruction is executed when the result is true, and not executed when the result is false.

#### 2.4 Memory

The  $\mu$ PD77017 has one instruction memory area (64K words  $\times$  32 bits) and two data memory areas (64K words  $\times$  16 bits each). It adopts Harvard-type architecture, with instruction memory area and data memory areas separated.

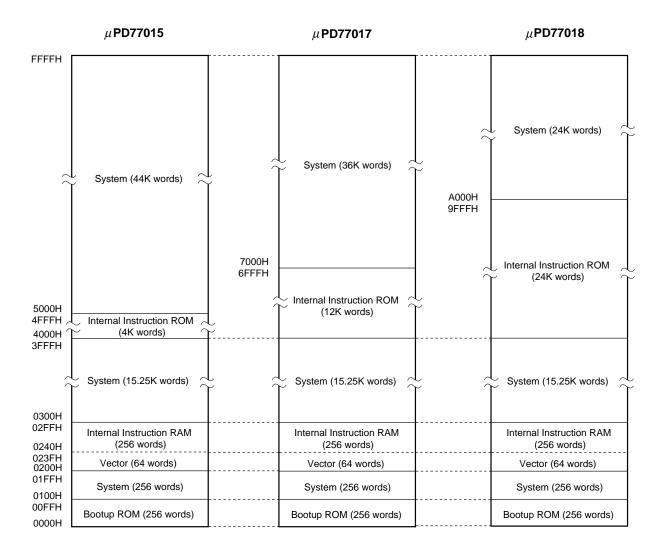
The  $\mu$ PD77017 has 2 sets of data addressing units, which are dedicated for addressing data memory area. Each addressing unit consists of four data pointers, four index registers, a modulo register and addressing ALU.

X memory area addresses are specified by DP0 to DP3, and Y memory area addresses are specified by DP4 to DP7. After memory access, DPn (with the same subscript), can be modified by DNn value. Modulo operation is performed with DMX for DP0 to DP3, with DMY for DP4 to DP7.

#### 2.4.1 Instruction RAM Outline

The  $\mu$ PD77015 has an instruction ROM (4K words × 32 bits) and instruction RAM( 256 words × 32 bits). The  $\mu$ PD77017 has an instruction ROM (12K words × 32 bits) and instruction RAM( 256 words × 32 bits). The  $\mu$ PD77018 has an instruction ROM (24K words × 32 bits) and instruction RAM( 256 words × 32 bits). A system vector area is assigned to 64 words of the instruction RAM. Internal instruction RAM is initialized and rewritten by boot program.

Boot up ROM contains the program loading instruction code to internal instruction RAM.



Caution When any data is accessed or stored to system address, normal operation of the device is not assured.

#### 2.4.2 Data Memory Outline

The  $\mu$ PD77015 has two data memory areas (64K words imes 16 bits each) in X and Y memory areas.

Each memory areas consists of 1K words  $\times$  16 bits data RAM and 2K words  $\times$  16 bits data ROM . As the  $\mu$ PD77017 has interface with the external data memory, 16 K words  $\times$  16 bits external data memory space can be add to X/Y memories.

The  $\mu$ PD77017 has two data memory areas (64K words  $\times$  16 bits each) in X and Y memory areas.

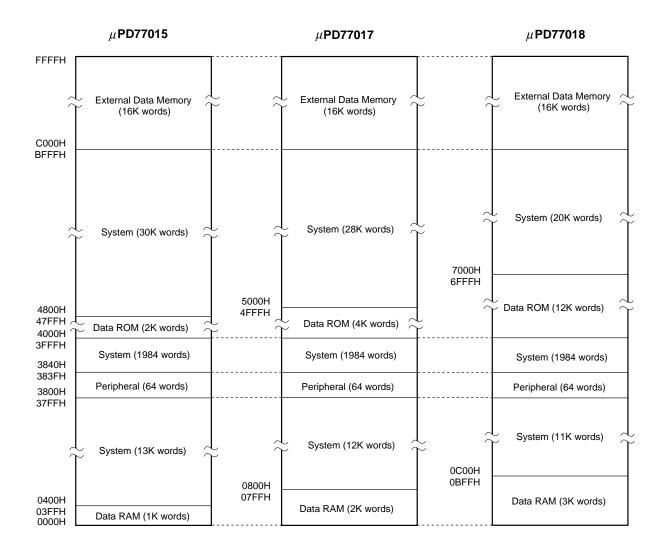
Each memory areas consists of 2K words  $\times$  16 bits data RAM and 4K words  $\times$ 16 bits data ROM . As the  $\mu$ PD77017 has interface with the external data memory, 16 K words  $\times$ 16 bits external data memory space can be add to X/Y memories.

The  $\mu$ PD77018 has two data memory areas (64K words  $\times$  16 bits each) in X and Y memory areas.

Each memory areas consists of 3K words  $\times$  16 bits data RAM and 12K words  $\times$ 16 bits data ROM. As the  $\mu$ PD77018 has interface with the external data memory, 16 K words  $\times$ 16 bits external data memory space can be add to X/Y memories.

Each data memory area includes on-chip peripheral area which consists of 64 words.

When the external data memory area is accessed, instruction cycle can be 2 or more by wait function.



### Caution When any data is accessed or stored to system address, normal operation of the device is not assured.

#### 2.4.3 Data Memory Addressing

There are following two types of data memory addressing.

• Direct addressing

The address is specified in the instruction field.

Indirect addressing

The address is specified by the data pointer (DP). DP can get a bit reverse before addressing. It can update the DP value after accessing data memory.

#### 2.5 On-chip Peripheral Circuit

The  $\mu$ PD77017 includes serial interface, host interface, general input/output ports and wait cycle registers. They are mapped in both X and Y memory areas, and are accessed as memory mapped I/O by the  $\mu$ PD77017 CPU.

#### 2.5.1 Serial Interface Outline

The  $\mu$ PD77017 has 2 channel serial interfaces. Serial I/O clock must be provided from external. Frame length can be programmed independently to be 8 bits or 16 bits. MSB first or LSB first can also be selected. Data is input/output by hand shaking for an external device, and by interrupts, polling or wait function in internal.

#### 2.5.2 Host Interface Outline

The  $\mu$ PD77017 has 8 bits parallel ports as host interface to input/output data to and from host CPU and DMA controller. When an external device accesses host interface, HA0 and HA1 pins; which are host address input pins; specifies bit 15 to bit 8 and bit 7 to bit 0. The  $\mu$ PD77017 includes 3 registers consisting of 16 bits, which are dedicated for input data, output data and status. The  $\mu$ PD77017 has three types of interface method for internal and external data; interrupts, polling and wait function.

#### 2.5.3 General Input/output Ports Outline

General input/output ports consist of 4 bits. User can set each port as input or output. The  $\mu$ PD77017 includes two registers. One is 4 bits register for input/output data, and the other is 16 bits for control.

#### 2.5.4 Wait Cycle Register

The wait cycle registers consist of 16 bits. It is used to set wait cycle number when external memory is accessed. When external data memory area (C000H - FFFFH) is accessed, 0, 1, 3, or 7 wait cycle can be set. When external data memory area is accessed, wait cycle can be also set by WAIT pin.

#### 3. INSTRUCTIONS

#### 3.1 Outline

All  $\mu$ PD77017 instructions are one-word instructions, consisting of 32 bits. And they are executed in 30 ns (min.) per instruction. There are following 9 instruction types.

#### (1) Trinomial instructions

: specify the Acc operation. 3 of general registers are specified optionally as the operation object.

#### (2) Dyadic operation instructions

: specify the Acc, ALU or shifter operation. 2 of general registers are specified optionally as the operation object. Some instructions can specify a general register and immediate data.

#### (3) Monadic operation instructions

: specify operations by ALU. 1 general register is specified optionally as the operation object.

#### (4) Load/store instructions

: transfer 16 bits data from memory to general registers, from general registers to memory and between general registers.

#### (5) Inter-register transfer instructions

: transfer data between general register and other registers.

#### (6) Immediate data set instructions

: set immediate data at general registers or each registers of address operation unit.

#### (7) Branch instructions

: specify the direction of the program flow.

#### (8) Hardware loop instructions

: specify times of instruction repeating.

#### (9) Control Instructions

: specify the control program.

#### 3.2 Instruction Set and Operation

An operation is written according to the rules for expressing. An expression of instructions having two or more descriptions can have only one selected.

#### (a) Expressions and selectable registers

Expression and selectable registers are shown as follows.

Expression	Selectable registers
ro, ro', ro"	R0 - R7
rl, rl'	ROL - R7L
rh, rh'	R0H - R7H
re	R0E - R7E
reh	R0EH - R7EH
dp	DP0 - DP7
dn	DN0 - DN7
dm	DMX, DMY
dpx	DP0 - DP3
dpy	DP4 - DP7
dpx_mod	DPn, DPn++, DPn, DPn##, DPn%%, !DPn## (n = 0 - 3)
dpy_mod	DPn, DPn++, DPn, DPn##, DPn%%, !DPn## (n = 4 - 7)
dp_imm	DPn##imm (n = 0 - 7)
***	content of memory address ×××
	<b>Example</b> When the content of DP0 register is 1000, *DP0 shows the content of memory address 1000.

#### (b) Modifying data pointers

Data pointers are modified after memory access. The results are valid immediately after instruction execution. It is impossible to modify without memory access.

Description	Operation
DPn	No operation: DPn value does not change.
DPn++	$DPn \leftarrow DPn+1$
DPn	$DPn \leftarrow DPn-1$
DPn##	DPn ← DPn + DNn: Adds DN0-DN7 corresponding to DP0-DP7 <b>Example</b> DP0 ← DP0 + DN0
DPn%%	(n = 0 - 3)       DPn = ((DPL + DNn )mod (DMX + 1)) + DPH         (n = 4 - 7)       DPn = ((DPL + DNn )mod (DMY + 1)) + DPH
!DPn##	Access memory after DPn value is bit-reversed After memory access, DPn ← DPn + DNn
DPn##imm	$DPn \leftarrow DPn$ + imm

#### (c) Concurrent processing instructions

 $\bigcirc$  shows concurrent processing instruction.

Instruction names are shown in abbreviation.

TRI	:	Trinomial
DYAD	:	Dyadic
MONAD	:	Monadic
TRANS	:	Inter-register transfer
IMM	:	Immediate data set
BR	:	Branch
LOOP	:	Hardware loop
CTR	:	Control

#### (d) State of Overflow flag (OV)

The following marks show the  $\mu$ PD77017 overflow flag state.

- •: Not affected
- $\updownarrow$ : 1 is set when the result of operation is overflow.

Caution If overflow does not occur after operation, OV is not reset, and keeps the state before operation.

NEC

# µPD77015, 77017, 77018

#### $\mu$ PD77017 INSTRUCTION SET

				Concurrent Writing Processing										
	Name	Mnemonic	Operation	TRI.	DYAD.	MONAD.	Load/ store	TRANS.	IMM.	BR.	LOOP.	CTL.	OV	
	Multiply add	ro = ro + rh*rh'	$ro \leftarrow ro+rh*rh'$				0						\$	
	Multiply sub	ro = ro-rh*rh'	$ro \leftarrow ro-rh*rh'$				0						\$	
Trinomial	Sign unsign Multiply add	ro = ro + rh∗rl (rl should be a plus integral number.)	ro ← ro+rh∗rl				0						\$	
	Unsign unsign Multiply add	ro=ro+rl*rl' (rl and rl' should be a plus integral number.)	ro ← ro+rl*rl'				0						\$	
	1 bit shift Multiply add	ro=(ro>>1)+rh*rh'	$ro \leftarrow \frac{ro}{2} + rh * rh'$				0						\$	
	16 bits shift Multiply add	ro = (ro>>16)+rh*rh'	$ro \leftarrow \frac{ro}{2^{16}} + rh * rh'$				0						•	
	Multiply	ro=rh*rh'	$ro \leftarrow rh*rh'$				0						•	
	Add	ro"=ro+ro'	ro" ← ro+ro'				0						\$	
	Immediate add	ro'=ro+imm	ro' ← ro+imm (imm≠1)										\$	
	Sub	ro"=ro-ro'	ro" ← ro−ro'				0						\$	
	Immediate sub	ro'=ro-imm	ro' ← ro–imm (imm≠1)										\$	
Dyadic	Arithmetic right shift	ro'=ro SRA rl	$ro' \leftarrow ro >> rl$				0						•	
	Immediate arithmetic right shift	ro'=ro SRA imm	$ro' \leftarrow ro >> imm$										•	
	Logic right shift	ro'=ro SRL rl	$ro' \leftarrow ro >> rl$				0						•	
	Immediate Logic right shift	ro'=ro SRL imm	$ro' \leftarrow ro >> imm$										•	
	Logic left shift	ro'=ro SLL rl	ro' ← ro << rl				0						•	
	Immediate logic left shift	ro'=ro SLL imm	$ro' \leftarrow ro << imm$										•	

				Concurrent Writing Processing										
	Name	Mnemonic	Operation	TRI.	DYAD.	MONAD.	Load/ store	TRANS.	IMM.	BR.	LOOP.	CTL.	. ov	
	And	ro" = ro & ro'	$ro" \leftarrow ro \& ro'$				0							
	Immediate and	ro' = ro & imm	$ro' \leftarrow ro \& imm$											
	Or	ro" = ro   ro'	$ro" \leftarrow ro \mid ro'$				0							
Dyadic	Immediate or	ro' = ro   imm	$ro' \leftarrow ro \mid imm$										•	
Dyaalo	Exclusive or	ro" = ro ^ ro'	ro" ← ro ^ ro'				0							
	Immediate exclusive or	ro = ro ^ imm	$ro \leftarrow ro \land imm$											
	Less than	ro" = LT(ro, ro')	if(ro <ro') {ro" ← 000000001H} else {ro" ← 000000000H}</ro') 				0						•	
	Clear	CLR(ro)	$ro \leftarrow 0H$				0					0		
	Increment	ro' = ro + 1	ro' ← ro + 1				0					0	\$	
	Decrement	ro' = ro - 1	$ro' \leftarrow ro - 1$				0					0	\$	
	Absolute	ro' = ABS (ro)	if (ro<0) {ro' $\leftarrow$ -ro} else {ro' $\leftarrow$ ro}				0					0	\$	
	One's complement	ro' = ~ro	$ro' \leftarrow ro$				0					0	•	
	Two's complement	ro' = -ro	ro' ← −ro				0					0	\$	
Monadic	Clip	ro' = CLIP (ro)	if (ro>007FFFFFFH) {ro' $\leftarrow$ 007FFFFFFH] else if, (ro <ff8000000h) {ro' <math>\leftarrow</math> FF80000000H} else {ro' <math>\leftarrow</math> ro}</ff8000000h) 				0					0	\$	
	Round	ro' = ROUND (ro)	if (ro>007FFF0000H) {ro' $\leftarrow$ 007FFF0000H} else if, (ro>FF8000000H) {ro' $\leftarrow$ FF80000000H} else {ro' $\leftarrow$ (ro + 8000H) & FFFFFF0000H}				0					0	\$	
	Exponent	ro' = EXP (ro)	$ro' \leftarrow log_2  (\frac{1}{ro})$				0					0	•	
	Substitution	ro' = ro	ro' ← ro	1			0					0		

						Cor	ncurrent V	Vriting Pro	cessing				Flag
	Name	Mnemonic	Operation	TRI.	DYAD.	MONAD.	Load/ store	TRANS.	IMM.	BR.	LOOP.	CTL.	ov
	Cumulation	ro'+ = ro	ro' ← ro'+ro				0					0	$\uparrow$
	Degression	ro'- = ro	ro' ← ro'−ro				0					0	$\uparrow$
	Division	ro'/ = ro	if (sign(ro')==sign(ro)) {ro' ← (ro'-ro)<<1} else {ro' ← (ro'+ro)< if (sign(ro')==0 {ro' ← ro'+1}				0					0	€
	Parallel load/store	ro=*dpx_mod ro'=*dpy_mod	$ro \leftarrow *dpx, ro' \leftarrow *dpy$										
	Note 1, Note 2	ro=*dpx_mod *dpy_mod=rh	$ro \leftarrow *dpx, *dpy \leftarrow rh$		0	0							
		*dpx_mod=rh ro=*dpy_mod	$*dpx \leftarrow rh, ro \leftarrow *dpy$		Ŭ								
Load/store		*dpx_mod=rh *dpy_mod=rh'	$*dpx \leftarrow rh, *dpy \leftarrow rh'$										
Loudistore	Section load/store	dest=*dpx_mod dest'=*dpy_mod	$dest \gets *dpx,  dest' \gets *dpy$										
	Note 1, Note 2, Note 3	dest=*dpx_mod *dpy_mod=source	$dest \gets *dpx, *dpy \gets source$	-									
		*dpx_mod=source dest=*dpy_mod	$*dpx \leftarrow source, dest \leftarrow *dpy$										
		*dpx_mod=source *dpy_mod=source'	$*dpx \leftarrow source, *dpy \leftarrow source'$										

**Note 1.** One or both of a mnemonic pair can be written.

- **2.** After execution of load/store, data is modified by mod.
- 3. One of following mnemonic should be selected: dest, dest' = {ro, reh, re, rh, rl}, source, source' = {re, rh, rl}.

Z

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						Cor	ncurrent V	Vriting Pro	cessing				Flag
	Name	Mnemonic	Operation	TRI.	DYAD.	MONAD.	Load/ store	TRANS.	IMM.	BR.	LOOP.	CTL.	OV
	Direct addressing load/store <b>Note 1</b>	dest = *addr	dest ← *addr										
Load/store		*addr = source	∗addr ← source										
2000,01010	Immediate index	dest = *dp_imm	dest ← *dp										
	load/store Note 2	*dp_imm = source	$*dp \leftarrow source$										
Inter-register	Inter-register transfer Note 3	dest = rl	dest $\leftarrow$ rl									0	
transfer		rl = source	$rl \leftarrow source$										
	Immediate data set	rl = imm (provided imm = 0-0xFFFF)	rl ← imm										
Immediate data set		dp = imm (provided imm = 0-0xFFFF)	dp ← imm										
		dn = imm (provided imm = 0-0xFFFF)	dn ← imm										
		dm = imm (provided imm = 1-0xFFFF)	dm ← imm										

0: X-0xFFFF:X memory 0: Y-0xFFFF:Y memory

**Note 1.** One of following mnemonic should be selected: dest = {ro, reh, re, rh, rl}, source = {re, rh, rl}, add =  $\begin{cases} 0. & -0. \\ 0. & -0. \end{cases}$ 

 $\textbf{2.} \quad \text{One of following mnemonic should be selected: } dest = \{ \text{ro, reh, re, rh, rl} \}, \ \text{source} = \{ \text{re, rh, rl} \}.$ 

3. Any register except general registers should be selected as dest or source.

						Cor	ncurrent \	Vriting Proc	cessing				Flag
	Name	Mnemonic	Operation	TRI.	DYAD.	MONAD.	Load/ store	TRANS.	IMM.	BR.	LOOP.	CTL.	ov
	Jump	JMP imm	$PC \gets imm$									0	
	Inter-register indirect jump	JMP dp	$PC \leftarrow dp$									0	$\bullet$
	Subroutine call	CALL imm	$\begin{array}{l} SP \leftarrow SP + 1 \\ STK \leftarrow PC + 1 \\ PC \leftarrow imm \end{array}$									0	•
Branch	Inter-register indirect subroutine call	CALL dp	$\begin{array}{l} SP \leftarrow SP + 1 \\ STK \leftarrow PC + 1 \\ PC \leftarrow dp \end{array}$									0	•
	Return	RET	$PC \leftarrow STK$ $SP \leftarrow SP - 1$									0	•
	Return from interrupt	RETI	$PC \leftarrow STK$ $STK \leftarrow SP - 1$ Restore the interrupt enable flag									0	•
	Repeat	REP count	$\begin{array}{ccc} \text{start} & \text{RC} \leftarrow \text{count} \\ & \text{RF} \leftarrow 0 \\ \text{repeat} & \text{PC} \leftarrow \text{PC} \\ & \text{RC} \leftarrow \text{RC} - 1 \\ \text{end} & \text{PC} \leftarrow \text{PC} + 1 \\ & \text{RF} \leftarrow 1 \end{array}$										•
Hardware loop	Loop	LOOP count (Mnemonics more than two lines)	$\begin{array}{ccc} \text{start} & \text{RC} \leftarrow \text{count} \\ & \text{RF} \leftarrow 0 \\ \text{repeat} & \text{PC} \leftarrow \text{PC} \\ & \text{RC} \leftarrow \text{RC} - 1 \\ \text{end} & \text{PC} \leftarrow \text{PC} + 1 \\ & \text{RF} \leftarrow 1 \end{array}$										•
	Loop pop	LPOP	$\begin{array}{l} LC \leftarrow LSR3 \\ LE \leftarrow LSR2 \\ LS \leftarrow LSR1 \\ LSP \leftarrow LSP-1 \end{array}$										•
	No operation	NOP	$PC \leftarrow PC + 1$										
	Halt	HALT	CPU stop Note1										
Control	Stop	STOP	CPU, PLL, OSC Stop Note2										lacksquare
	lf	IF (ro cond)	Conditional judge			0		0		0			
	Forget interrupt	FINT	Forget interrupt requests										$\bullet$

- Note 1. The HALT instruction causes all function except for clock and PLL to halt. The system is placed in much less power consumption mode.
   The contents of internal registers and memories are maintained.
   HALT is released by interrupt input. It takes several system clock to recover.
  - The STOP instruction causes all function including clock and PLL to stop. The system is placed in a minimum-power consumption mode. The contents of internal registers and memories are not maintained. After the STOP instruction is executed, pin status is maintained. STOP is released by hardware reset. It takes a few ms to recover.

#### 4. ELECTRICAL SPECIFICATIONS

#### Absolute Maximum Ratings ( $T_A = +25$ °C)

Parameters	Symbol	Conditions	Ratings	Unit
Power supply voltage	Vdd		-0.5 to +4.6	V
Input voltage	Vı	$2.7 \text{ V} \leq \text{V}_{\text{DD}} \leq 3.6 \text{ V}$	–0.5 to +4.1 V⊨< Vpd +0.5 V	V
Output voltage	Vo		-0.5 to +4.6	V
Storage temperature	Tstg		-65 to +150	°C
Operating ambient temperature	TA		-40 to +85	°C

#### Caution Exposure to Absolute Maximum Ratings for extended periods may affect device reliability; exceeding the ratings could cause permanent damage. The parameters apply independently. The device should be operated within the limits specified under DC and AC Characteristics.

#### **Recommended Operating Conditions**

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Operating voltage	Vdd		2.7	3.0	3.6	V
Input voltage	Vi		0		Vdd	V

#### Capacitance (T<sub>A</sub> = +25 $^{\circ}$ C, V<sub>DD</sub> = 0 V)

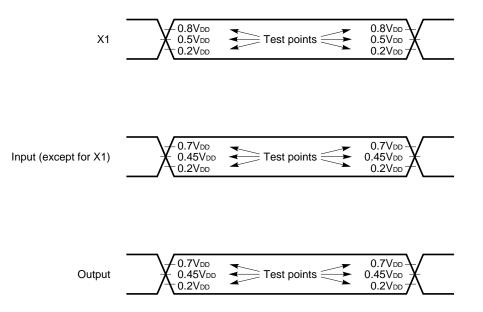
Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input capacitance	Cı	f = 1 MHz		10		pF
Output capacitance	Co	Unmeasured pins returned to 0 V.		10		pF
Input/output capacitance	Сю			10		PF

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
High level input voltage	Vін	Except for X1	0.7Vdd		Vdd	V
High level X1 input voltage	Vінс	X1 input	0.8Vdd		Vdd	V
Low level input voltage	VIL		0		0.2Vdd	V
High level output voltage	Vон	Іон = -2.0 mA	0.7Vdd			V
		Іон = –100 <i>µ</i> А	0.8Vdd			V
Low level output voltage	Vol	IoL = 2.0 mA			0.2Vdd	V
High level input leak current	Ілн	Except for TDI, TMS, VI = VDD			10	μA
Low level input leak current	Тліс	Except for TDI, TMS, $V_1 = 0 V$			-10	μA
Pull-up pin current	Ін	TDI, TMS, 0 V $\leq$ VI $\leq$ VDD			-250	μA
Power supply current	DD <sup>Note 1</sup>	Active mode, $t_{cc}$ = 30 ns V <sub>IH</sub> = V <sub>DD</sub> , V <sub>IL</sub> = 0 V, no load		Note 2	Note 3	mA
	Іррн	HALT mode, $t_{cc}$ = 240 ns V <sub>IH</sub> = V <sub>DD</sub> , V <sub>IL</sub> = 0 V, no load			Note 4	mA
	Idds	STOP mode, VIH = VDD, VIL = 0 V, no load			100	μA

#### DC Characteristics (T<sub>A</sub> = -40 to +85 °C, V<sub>DD</sub> = 2.7 to 3.6 V)

- **Note 1.** The TYP. value is measured when a general program is executed, and V<sub>DD</sub> = 3 V condition. The MAX. value is measured when a special program that max. switching required is executed, and V<sub>DD</sub> = 3.6 V condition.
  - **2.** μPD77015: 40 mA, μPD77017: 45 mA, μPD77018: 50 mA
  - **3.** μPD77015: 120 mA, μPD77017: 150 mA, μPD77018: 170 mA
  - **4.** μPD77015: 8 mA, μPD77017: 10 mA, μPD77018: 15 mA

#### **AC Timing Test Points**



#### AC Characteristics (T<sub>A</sub> = -40 to +85 °C, V<sub>DD</sub> = 2.7 to 3.6 V)

#### Clock

#### **Required Timing Condition**

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
CLKIN cycle time	tccx	PLL multiple rate: 1	30		35.7	ns
		PLL multiple rate: 2	60		71.4	ns
		PLL multiple rate: 4	120		143	ns
		PLL multiple rate: 8	240		286	ns
CLKIN high level width	t <sub>wCXH</sub>		13.5		tccx - 13.5 - 2t <sub>rfCx</sub> Note	ns
CLKIN low level width	twCXL		13.5		tccx - 13.5 - 2t <sub>rfCx</sub> Note	ns
CLKIN rise/fall time	trfCX				15	ns

#### **Note** $0.5tccx - trfcx \ge 13.5$ (MIN.)

#### Switching Characteristics

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Internal clock cycle time	tcC	Active mode		t <sub>cCX</sub> /N <sup>Note</sup>		ns
		HALT mode		8tccx/NNote		ns
CLKOUT cycle time	tcco			tcC		ns
CLKOUT level width	twco		0.5tcco – 5			ns
CLKOUT rise/fall time	trfCO				5	ns

Note N: PLL multiple rate (N = 1, 2, 4, 8)

#### ★

#### Oscillator Circuit

Resonator	Recommended Circuit
Ceramic or crystal resonator	$\begin{array}{c c} x_1 & x_2 \\ \hline \\ c_1 & \hline \\ \hline$
External clock	X1 X2 External Clock Supply NU NU: Not Use. Leave Open.

- Cautions 1. When using system clock oscillator, wire the portion enclosed in broken lines in the figure as follows to avoid adverse influences on the wiring capacitance:
  - Keep the wiring length as short as possible.
  - Do not cross the wiring over the other signal lines.
  - Do not route the wiring in the vicinity of lines through which a high fluctuating current flows.
  - Always keep the ground point of the capacitor of the oscillator circuit at the same potential as GND.
  - Do not connect the power source pattern through which a high current flows.
  - Do not extract signals from the oscillator.
  - 2. When using ceramic resonator or crystal resonator, frequency multiple rate should be specified to as 1 by mask option. The device does not operate in other frequency multiple rate.

#### \* Recommended Oscillator Circuit Constants

	Manufacturer Name	Part Number	Fraguanay (MHz)	Recommende	ed Constants
		Fait Nulliber	Frequency (MHz)	C1 [pF]	C2 [pF]
Ceramic Resonator	TDK	CCR33.0MC6	33.0	Internal	
	MURATA	CSA33.00MXZ040		5	5
	Manufacturing	CST33.00MXW040		Internal	
		CSACV33.00MX040		5	5
				Internal	
Crystal Resonator	DAISHINKU	AT-49		10	10
		DSX840G			

**Remark** Recommended oscillator circuit constants may differ on the wiring capacitance of the target board the customer designed. When using a resonator for the target system, let manufacturer evaluate.

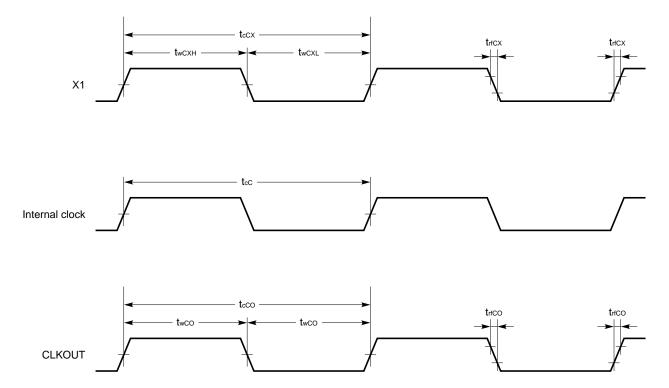
#### **Reset**, Interrupt

#### **Required Timing Condition**

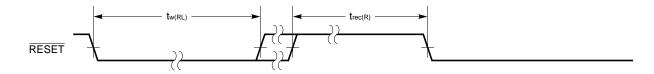
Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
RESET low level width	tw(RL)	Crystal resonator is input, at power on or STOP mode	3Note 1			ms
		External clock is input, at power on or STOP mode	100 <sup>Note</sup> 1			μs
		Active mode or HALT mode	4tccNote 2			ns
RESET recovery time	trec(R)		4tcc			ns
INT1-INT4 low level width	tw(INTL)		3tccNote 2			ns
INT1-INT4 recovery time	trec(INT)		3t₀c			ns

- **Note 1.** The tw(RL) indicates a time between crystal resonator or oscillator starts to provide clock and PLL becomes stable. The tw(RL) depends on the rating of crystal resonator or oscillator. At power on, the tw(RL) is measured after the point that power supply voltage reaches to 0.8 VDD.
  - 2. Note that, during HALT mode, tcc is extended to 8 times as long as that of Active mode.

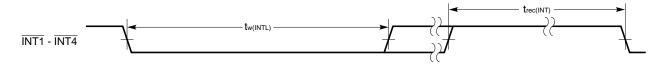
## **Clock Input/Output Timing**



#### **Reset Timing**



## Interrupt Timing



## **External Data Memory Access**

## **Required Timing Condition**

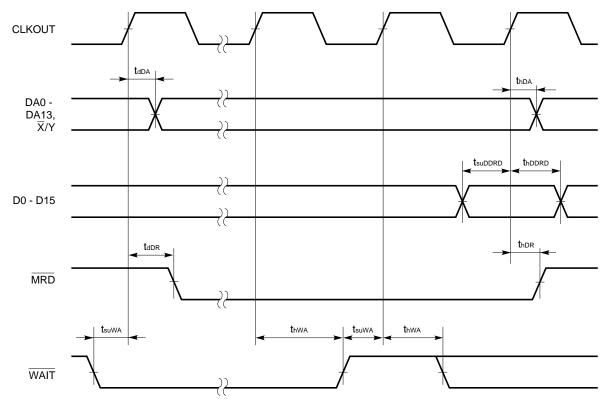
Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Read data setup time	tsuDDRD		15			ns
Read data hold time	thddrd		0			ns
WAIT setup time	<b>t</b> suWA		12			ns
WAIT hold time	thWA		0			ns

#### Switching Characteristics

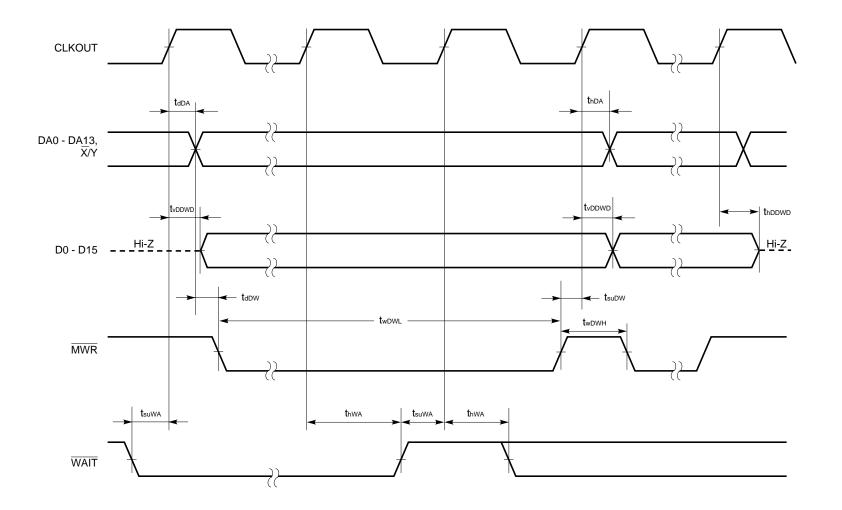
Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Address output delay time	tdDA				8	ns
Address output hold time	<b>t</b> hDA		0			ns
MRD output delay time	tddr				8	ns
MRD hold time	thDR		0			ns
Write data output valid time	tvddwd				16	ns
Write data output hold time	thddwd		0			ns
MWR output delay time	tddw		0.25tcc – 5			ns
MWR setup time	tsuDW		0			ns
MWR low level width	twdwl		0.5tcc − 3 + t <sub>cDW</sub> Note			ns
MWR high level width	t <sub>wDWH</sub>		0.5tcc – 5			ns

#### Note tcDw: Data wait cycle

#### External Data Memory Access Timing (Read)



External Data Memory Access Timing (Write)



#### **Bus Arbitration**

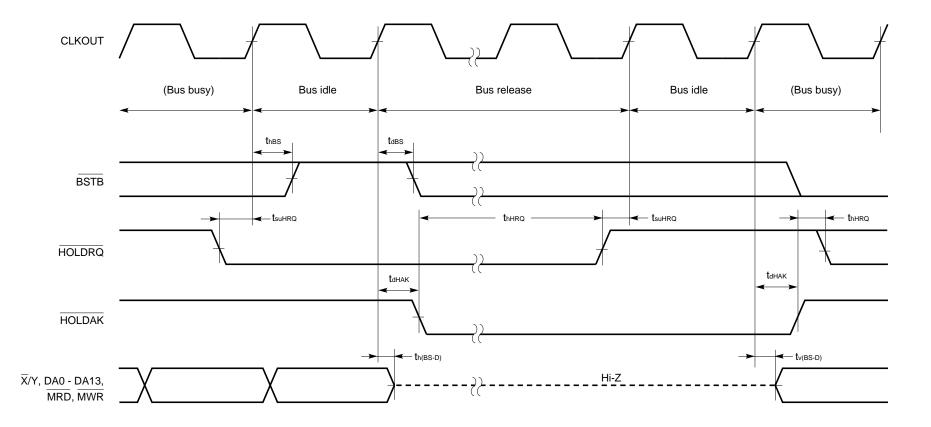
## **Required Timing Condition**

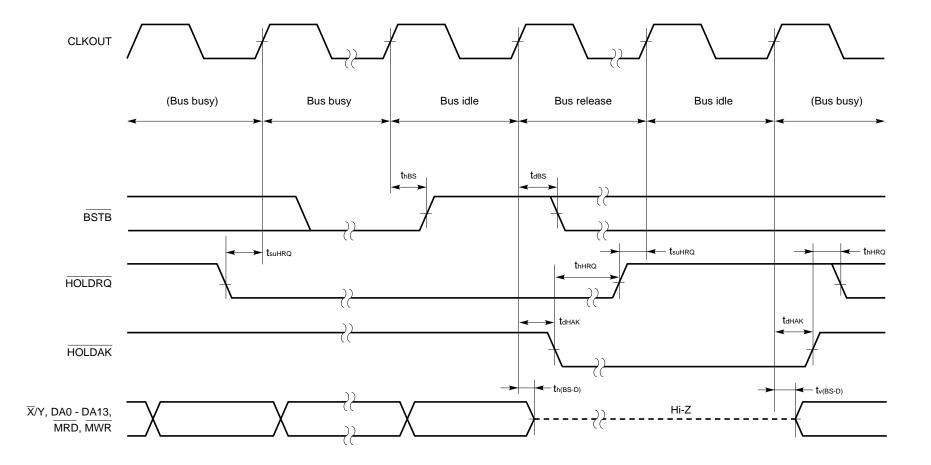
Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
HOLDRQ setup time	<b>t</b> suHRQ		12			ns
HOLDRQ hold time	<b>t</b> hHRQ		0			ns

## Switching Characteristics

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
BSTB hold time	<b>t</b> hBS		0			ns
BSTB output delay time	t <sub>dBS</sub>				12	ns
HOLDAK output delay time	tdнак				12	ns
Data hold time when bus arbitration	th(BS-D)				30	ns
Data valid time after bus arbitration	tv(BS-D)				15	ns

Bus Arbitration Timing (Bus idle)





#### **Serial Interface**

#### **Required Timing Condition**

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
SCK input cycle time	tesc		2tcc			ns
SCK input high/low level width	twsc		25			ns
SCK input rise/fall time	trfsc				20	ns
SOEN recovery time	trecSOE		20			ns
SOEN hold time	thSOE		0			ns
SIEN recovery time	trecSIE		20			ns
SIEN hold time	thSIE		0			ns
SI setup time	tsuSI		20			ns
SI hold time	thsi		0			ns

#### **Switching Characteristics**

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
SORQ output delay time	tdsor				30	ns
SORQ hold time	thsor		0			ns
SO valid time	tvso				30	ns
SO hold time	<b>t</b> hSO		0			ns
SIAK output delay time	tdsia				30	ns
SIAK hold time	thSIA		0			ns

#### Notes for Serial Clock

★

Serial clock inputs SCK1 and SCK2 are sensitive to any kind of interfering signals (noise on power supply, induced voltage, etc.). Spurious signals can cause malfunction of the device. Special care for the serial clock design should be taken. Careful grounding, decoupling and short wiring of SCK1 and SCK2 are recommended. Intersection of SCK1 and SCK2 with other serial interface lines or close wiring to lines carrying high frequency signals or large changing currents should be avoided.

It considers for the serial clock to make a waveform stable especially about the rising and falling.

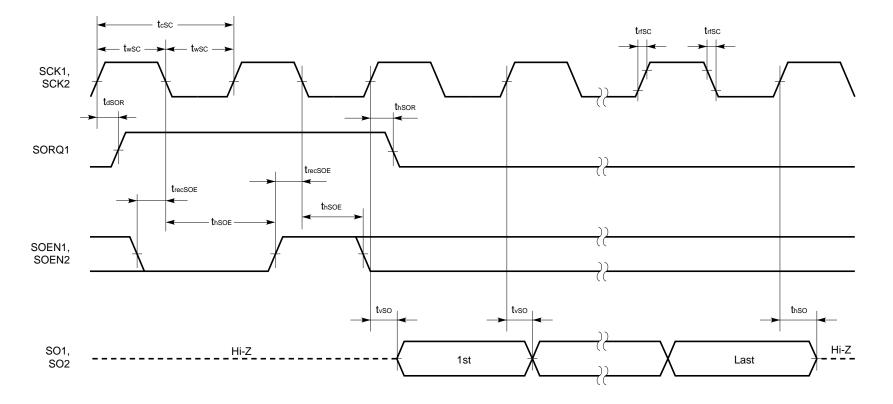


Example 1. good example Straight rising form and falling form

**Example 2. no good example** It doesn't bound. It doesn't make noise one above another.

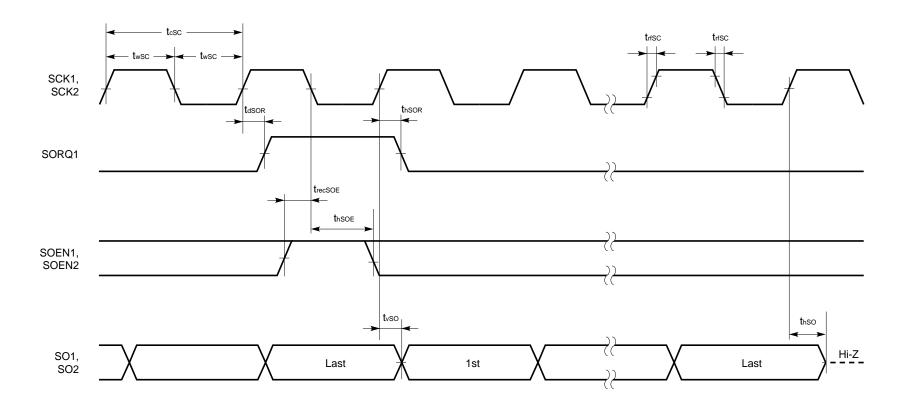
**Example 3. no good example** It doesn't make a stair stepping.

## Serial Output Timing 1

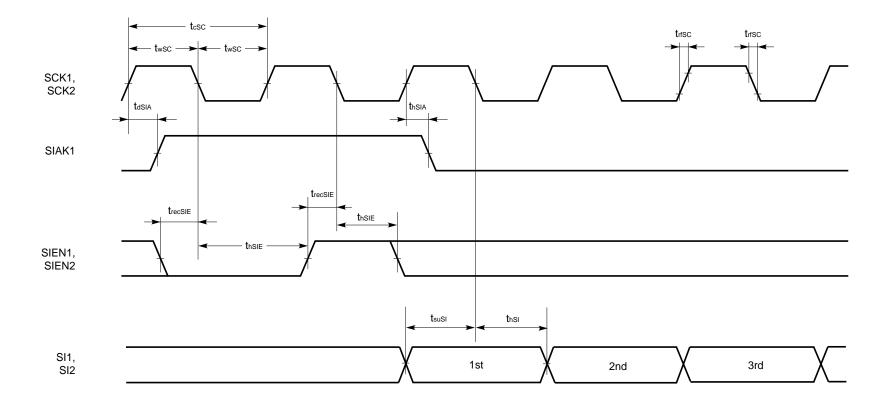


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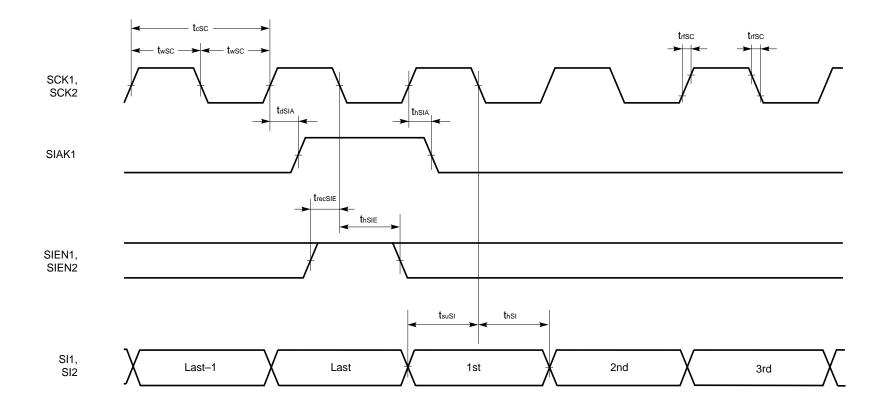
Serial Output Timing 2 (Continual output)



46



Serial Input Timing 2 (Continual input)



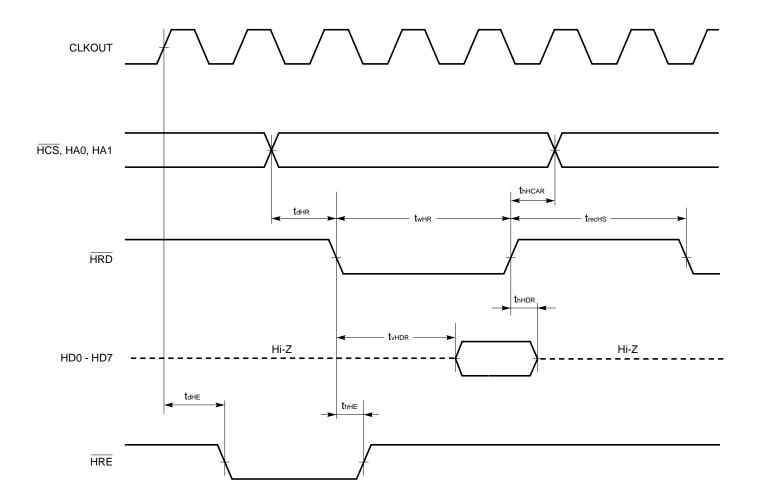
#### Host Interface

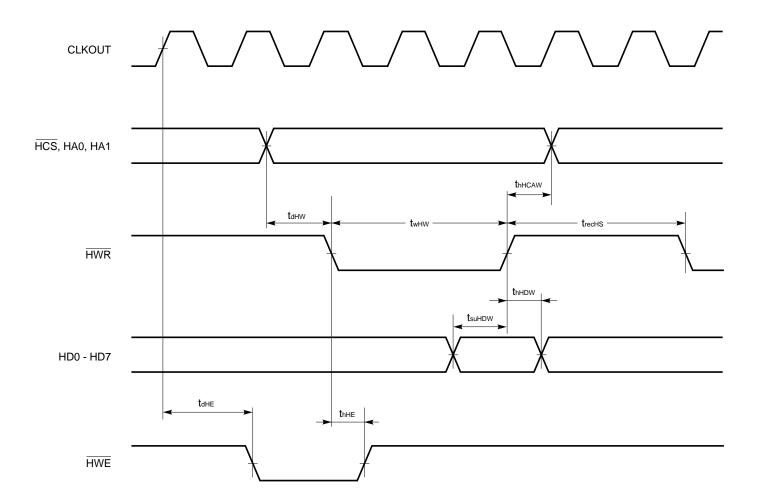
## **Required Timing Condition**

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
HRD delay time	tdHR		0			ns
HRD width	twhr		2tcc			ns
HCS, HA0, HA1 read hold time	thhcar		0			ns
$\overline{\text{HCS}}$ , HA0, HA1 write hold time	thHCAW		0			ns
HRD, HWR recovery time	trecHS		2tcc			ns
HWR delay time	tанw		0			ns
HWR width	twнw		2tcc			ns
HWR hold time	thhdw		0			ns
HWR setup time	tsuHDW		20			ns

## Switching Characteristics

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
HRE, HWE output delay time	tане				30	ns
HRE, HWE hold time	thHE				30	ns
HRD valid time	t <sub>vHDR</sub>				30	ns
HRD hold time	thhdr		0			ns





## **General Input/Output Ports**

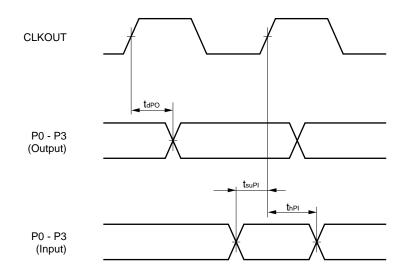
## **Required Timing Condition**

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Port input setup time	tsuPl		20			ns
Port input hold time	thPl		10			ns

#### Switching Characteristics

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Port output delay time	t <sub>dPO</sub>		0		30	ns

## General Input/Output Ports Timing



## Debugging Interface (JTAG)

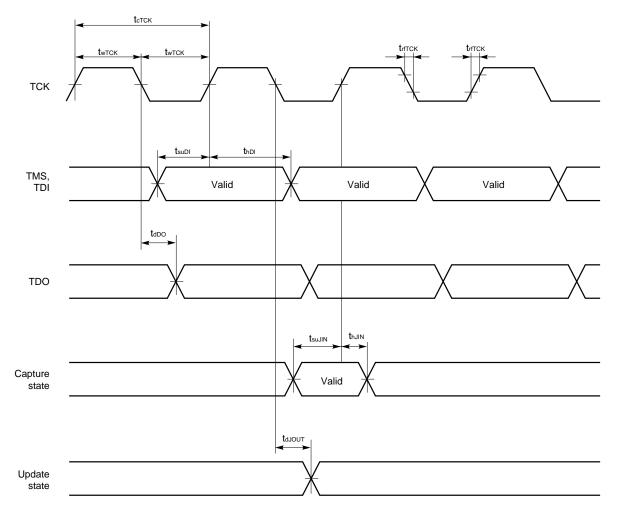
## **Required Timing Condition**

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
TCK cycle time	tстск		4tcc			ns
TCK high/low level width	t <sub>w</sub> тск		50			ns
TCK rise/fall time	<b>t</b> rfTCK				20	ns
TMS, TDI setup time	tsuDI		10			ns
TMS, TDI hold time	thDI		0			ns
Input pin setup time	tsuJIN		10			ns
Input pin hold time	thJIN		0			ns

#### Switching Characteristics

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
TDO output delay time	tado				30	ns
Output pin output delay time	tајоит				30	ns

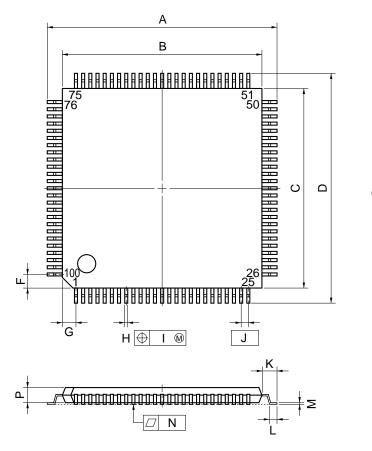
#### **Debugging Interface Timing**

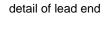


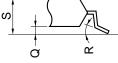
Remark For the details of JTAG, refer to "IEEE1149.1."

5. PACKAGE DRAWING

# 100 PIN PLASTIC TQFP (FINE PITCH) ( $\Box$ 14)







#### NOTE

Each lead centerline is located within 0.10 mm (0.004 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES	
Α	16.0±0.2	$0.630 \pm 0.008$	
В	14.0±0.2	$0.551^{+0.009}_{-0.008}$	
С	14.0±0.2	$0.551^{+0.009}_{-0.008}$	
D	16.0±0.2	$0.630 \pm 0.008$	
F	1.0	0.039	
G	1.0	0.039	
Н	$0.22^{+0.05}_{-0.04}$	0.009±0.002	
I	0.10	0.004	
J	0.5 (T.P.)	0.020 (T.P.)	
к	1.0±0.2	$0.039^{+0.009}_{-0.008}$	
L	0.5±0.2	$0.020^{+0.008}_{-0.009}$	
М	$0.145^{+0.055}_{-0.045}$	0.006±0.002	
N	0.10	0.004	
Ρ	1.0±0.1	$0.039^{+0.005}_{-0.004}$	
Q	0.1±0.05	0.004±0.002	
R	3°+7° -3°	3°+7° -3°	
S	1.27 MAX.	0.050 MAX.	
		S100GC-50-9EU-1	

#### 6. RECOMMENDED SOLDERING CONDITIONS

When soldering these products, it is highly recommended to observe the conditions as shown below. If other soldering processes are used, or if the soldering is performed under different conditions, please make sure to consult with our sales offices.

For more details, refer to our document "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (C10535E).

 $\mu$ PD77015GC-xxx-9EU: 100-pin plastic TQFP (FINE PITCH) (14mm  $\times$  14mm)

Process	Conditions	Symbol
Infrared ray reflow	Peak temperature: 235 °C or below (Package surface temperature),	IR35-107-2
	Reflow time: 30 seconds or less (at 210 °C or higher),	
	Maximum number of reflow processes : 2 times,	
	Exposure limit <sup>Note</sup> :7 days (10 hours pre-baking is required at 125 °C	
	afterwards).	
Vapor Phase Soldering	Peak temperature: 215 °C or below (Package surface temperature),	VP15-107-2
	Reflow time: 40 seconds or less (at 200 °C or higher),	
	Maximum number of reflow processes : 2 times,	
	Exposure limit $^{ m Note}$ : 7 days (10 hours pre-baking is required at 125 $^\circ m C$	
	afterwards).	
Partial heating method	Pin temperature : 300 °C or below,	
	Heat time : 3 seconds or less (Per each side of the device)	

- **Note** Maximum allowable time from taking the soldering package out of dry pack to soldering. Storage conditions: 25 °C and relative humidity of 65 % or less.
- Caution Apply only one kind of soldering condition to a device, except for "partial heating method", or the device will be damaged by heat stress.

#### $\mu$ PD77017GC-×××-9EU: 100-pin plastic TQFP (FINE PITCH) (14mm × 14mm) $\mu$ PD77018GC-×××-9EU: 100-pin plastic TQFP (FINE PITCH) (14mm × 14mm)

Process	Conditions	Symbol
Infrared ray reflow	Peak temperature: 235 °C or below (Package surface temperature),	IR35-103-2
	Reflow time: 30 seconds or less (at 210 °C or higher),	
	Maximum number of reflow processes : 2 times,	
	Exposure limit Note : 3 days (10 hours pre-baking is required at 125 °C	
	afterwards).	
Vapor Phase Soldering	Peak temperature: 215 °C or below (Package surface temperature),	VP15-103-2
	Reflow time: 40 seconds or less (at 200 °C or higher),	
	Maximum number of reflow processes : 2 times,	
	Exposure limit $^{ m Note}$ : 3 days (10 hours pre-baking is required at 125 $^{\circ} m C$	
	afterwards).	
Partial heating method	Pin temperature : 300 °C or below,	
	Heat time : 3 seconds or less (Per each side of the device)	

**Note** Maximum allowable time from taking the soldering package out of dry pack to soldering. Storage conditions: 25 °C and relative humidity of 65 % or less.

# Caution Apply only one kind of soldering condition to a device, except for "partial heating method", or the device will be damaged by heat stress.

## -NOTES FOR CMOS DEVICES

#### **(1)** PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note: Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

## **(2)** HANDLING OF UNUSED INPUT PINS FOR CMOS

Note: No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

## **③** STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note: Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

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NEC devices are classified into the following three quality grades:

"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

- Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
- Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
- Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices is "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact an NEC sales representative in advance.

Anti-radioactive design is not implemented in this product.